Abstract

The present study estimated the cracking phenomenon in as-plasma-sprayed hydroxyapatite coatings (HACs) after they were being subjected to the severe cutting conditions in the direction perpendicular to the coating/substrate interface. In order to evaluate the effects of substrate preheating on the occurrence of micro-cracks, the HACs were deposited at different initial substrate temperatures ($T_S = 20, 100$ and $200^\circ C$). The changes in phase composition and HA splat morphology with $T_S$ were observed and were correlated with the cracking occurrence. The results showed that severe cutting conditions introduced a localized cracking in the regions of HACs dominantly attributed to the brittle hydroxy-deficient amorphous calcium phosphate (ACP) phase. This effect was particularly observable in the HACs deposited without preheating of substrate. On the other hand, the preheating of substrate reduced the presence of micro-cracks and caused insignificant changes in the average local phase composition. In HACs deposited with preheating of substrate, the HA splats (of which HACs are composed) were thinner and recrystallized HA regions seemed smaller in size and more evenly distributed. These results implied potentially important roles of the HA splat formation mechanism on the distribution of ACP and recrystallized HA regions in the as-plasma-sprayed HACs and the cracking resistance of HACs.

Keywords: plasma spraying, hydroxyapatite coatings, stress, cracking, substrate preheating.

Many studies have indicated that the mechanical integrity of plasma-sprayed HACs in terms of the bonding strength (cohesion and adhesion) is of critical importance when these coatings are applied on the surface of biomedical implants, such as titanium alloy, stainless steel, etc. [1–9]. Considering the fact that the plasma-sprayed HACs are composed of many individual building blocks known as „HA splats“ [2,8,10], it is evident that the properties of the splat-substrate and splat-splat interfaces will generally affect the bonding strength of HACs. Saber-Samandary et al. have discussed that „it is the first layer of splats which determines the coating-substrate adhesion, while the coating cohesion is determined by the nature of the intersplat contact [8]. One of the effective ways for enhancement of splat-substrate and intersplat contacts (or bonding strength of HACs) is the substrate preheating. Most of the previous studies have shown the beneficial effects of the substrate preheating on the bonding strength of HACs [4,7]. However, other opinions exist [6], as well. It has been shown that preheating of substrate may promote: i) the recrystallization in HACs [4,8], ii) the formation of thinner HA splats [8] and iii) the change in thermal and residual stresses in HACs [6,7]. Morks and Kobayashi have emphasized the brittle nature of the amorphous calcium phosphate (ACP) phase [4]. In this regard and taking into account the statement of Saber-Samandari et al. about the nature of the intersplat contact [8], two neighboring amorphous HA splats should exhibit a minimum resistance towards the propagation of cracks.

In the present study, the last hypothesis was tested. Namely, if as-plasma-sprayed HACs are subjected to
the severe stress condition, such as cutting by using the handsaw, then the cracking of coating’s scale should occur and should be preferentially localized within the ACP regions. The HACs deposited at different initial substrate temperatures ($T_S$) were severely cut to qualitatively observe the effects of the substrate preheating on the cracking occurrence. In addition, the changes in the phase composition and splat morphology with $T_S$ were analysed and were correlated with the cracking phenomenon.

EXPERIMENTAL

Feedstock powder and substrate material

The substrate material was in the form of plates with dimensions of 25 mm x 50 mm x 3 mm. The plates were made of the implantation grade biomedical steel (AISI 316 LVM).

A commercially available HAP with particle size of 33 μm (XPT-D-703, Sulzer Metco, USA) was used for deposition of HACs. The particle size of HAP was listed according to manufacturer’s data sheets. The morphology of the feedstock HAP was observed by using the scanning electron microscopy (SEM) coupled with energy dispersive spectrometry (EDS). The composition of HAP was confirmed by using the EDS, X-ray fluorescence (XRF) spectrometry, and micro-Raman spectroscopy (MRS).

Atmospheric plasma spraying

The HAP was deposited onto the steel substrates by using the high power laminar plasma spray process (Plasma Jet Co, Serbia) [7,9]. Prior to deposition process, the steel plates were sand-blasted with 2 mm Al$_2$O$_3$ particles and cleaned in ultrasonic bath. The steel plates were then placed on a vertical disk with 200 mm in diameter. During the deposition process, the disk was rotating at $\sim$3.7 rev/s. The deposition of HAP was performed in two to three short intervals (7–10 s each) with pauses of few minutes between cycles. The HACs were deposited at different initial substrate temperatures $T_S = 20, 100$ and $200$ °C. Other parameters were kept constant during the plasma deposition process (Table 1). Other details related to deposition process are given in Refs. [7,9].

Table 1. Plasma deposition parameters (PJ-100 installation)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Plasma power, kW</td>
<td>52.0±1.5</td>
</tr>
<tr>
<td>Plasma voltage, V</td>
<td>120±2</td>
</tr>
<tr>
<td>Plasma current, A</td>
<td>430±5</td>
</tr>
<tr>
<td>Argon flow (plasma forming gas), dm$^3$/min</td>
<td>38.5±1.2</td>
</tr>
<tr>
<td>Stand-off distance (SOD)</td>
<td>100 mm</td>
</tr>
<tr>
<td>Nitrogen flow (plasma forming gas), dm$^3$/min</td>
<td>28.2±1.0</td>
</tr>
<tr>
<td>Air flow (HAP carrier gas), dm$^3$/min</td>
<td>8.0</td>
</tr>
<tr>
<td>Powder mass input, g/s</td>
<td>2.0±0.1</td>
</tr>
</tbody>
</table>

Characterization of HACs

In order to introduce the cracking of the coating’s scale, the HACs were cut in the direction depicted in Figure 1a by using a handsaw. Subsequently, the samples were hot-mounted in the bakelite resin with carbon filler (5.0±0.5 bar, 100±10 °C, 20±5 min). After hot-mounting, the cross-sections were ground with SiC water-proof abrasive papers (P-80, P-100, P-220, P-400, P-600, P-800, P-1000, P-1200, P-1500 and P-2000) and polished with Al$_2$O$_3$ water-based suspensions down to 1 μm. Other details related to sample preparation are given in Ref. [9].

Afterwards, the cross-sectional morphology of HACs was evaluated by using the SEM-EDS measurements, which were performed on a JEOL JSM-6610LV SEM coupled with Oxford Instruments X-Max SDD EDS (University of Belgrade, Faculty of Mining and Geology). During the analysis, the electron acceleration voltage of 20 kV and the tungsten filament were used. Prior to SEM-EDS analysis, the samples were coated with graphite particles in a vacuum chamber of a sputter coater device. The molar Ca/P ratio was measured along the thickness of HACs in steps of 5 μm by using the EDS line-scan analysis.

![Figure 1. Macrograph of typical as-plasma-sprayed HAC (a) and typical micrograph of HAC’s cross-section under the Raman microscope (b).](image-url)
After SEM-EDS, re-polished cross-sections of HACs were examined by using the MRS (Figure 1b). Raman scattering measurements were performed in a back-scattering micro-Raman configuration using Jobin Yvon T64000 triple spectrometer (gratings with ∼1800 grooves/mm), equipped with a confocal microscope, an x-y-z microscope stage and nitrogen cooled CCD detector. The Raman spectra were excited by the ∼514.5 nm line of Coherent Ar²/Kr² mixed laser, with output power of ∼50 mW. The spectral resolution of the Raman system was ∼2 cm⁻¹. The spectra were collected at room temperature in air, using 10× magnification objectives, with exposure time of 400 s. All spectra were calibrated against the strongest Raman band of polished Si wafer (∼520.6 cm⁻¹). In the case of each HAC, the Raman measurements were performed in the same region of the cross-section and within the same range of distances from the coating/substrate interface (100–150 µm).

In order to observe the morphology of HA splats, the HACs were cut in the direction shown in Figure 1a by using the diamond saw. Afterwards, the samples were: i) cold mounted in acrylic compound, ii) ground by using the SiC water-proof abrasive papers (P-800, P-1200 and P-2000) and iii) polished with Al₂O₃ water-based suspensions down to 1 µm. The micro-structural properties of cross-sections of HACs were then analyzed by using the inverted light microscope (LM) in the bright field mode (Reichert-Jung MEF3). Prior to analysis, the polished cross-sections were chemically etched in the ∼0.058 mol/l HNO₃ water solution. For each HAC, the etching time was 4–5 s. Considering the substantial difference between the solubility of the ACP and HA [11,12], the chemical etching was performed to reveal the distribution of ACP and recrystallized HA regions on the cross-sections of HACs, i.e., to delineate boundaries of HA splats.

RESULTS AND DISCUSSION

Feedstock powder (MRS, SEM-EDS)

When the HA powders of smaller sizes (20–45 µm) are deposited by using the atmospheric plasma spray process, they produce an enhanced lamellar structure of HA coatings in contrast to HA powders of larger sizes (75–125 µm) in which case the lamellar structure is barely distinguishable [13]. Therefore, the differences in morphology of HA splats formed from the HA powders of smaller sizes, introduced by preheating of substrate, can be more easily distinguished and evaluated compared to the HA splats formed from the HA powders of larger sizes. For this reason, the feedstock HA powder of relatively smaller size was used in the present study.

Figure 2a shows the spherical shape of the feedstock powder used in the present study. It should be
noted here that this figure represents the morphological appearance of the feedstock powder. In the present study, the determination of the feedstock powder size was not performed. The size of the feedstock powder was guaranteed by the manufacturer. The MRS analysis of the feedstock powder showed the presence of vibration modes of the phosphate group (PO$_4^{3-}$, Figure 2b) typically observed in HA powders [9,14,15]: i) O–P–O bending mode ($\nu_2$), ii) O–P–O bending mode ($\nu_4$), iii) P–O symmetric stretching mode ($\nu_3$) and iv) P–O asymmetric stretching mode ($\nu_3$). The OH$^-$ bands detected at $\sim$3572 cm$^{-1}$ are not presented in Figure 2b. On the other hand, the EDS analysis of the feedstock powder (Figure 2c) showed the values of the molar Ca/P ratio roughly between 1.3 and 1.6 (Figure 2d). This result implied that initial HA feedstock powder was probably calcium-deficient (non-stoichiometric). The Ca/P mole ratio of the stoichiometric HA is $\sim$1.667.

As a result of the thermal decomposition of HA feedstock powder in the high temperature plasma jet [15], the HACs may contain impurity phases with Ca/P mole ratios as follows [16]: i) $\alpha$- and $\beta$-tricalcium phosphate ($\alpha$- and $\beta$-TCP, Ca/P = 1.5), ii) oxyapatite/oxyhydroxyapatite (OA/OHA, Ca/P = 1.67), iii) tetracalcium phosphate (TTCP, Ca/P = 2.0), iv) calcium oxide (CaO, (Ca/P = $\infty$) and v) amorphous calcium phosphate (ACP, (Ca/P range 1.2–2.2). In the present study, the estimation of $\alpha$-TCP, $\beta$-TCP, and OA/OHA presence in deposited HACs based on the the Ca/P mole ratio was uncertain because the Ca/P mole ratios for these phases overlap with the observed Ca/P mole ratio for HAP (1.3–1.6, Figure 2d). The only phases that may show distinctively different Ca/P mole ratio are ACP (1.2–2.2), TTCP (2.0) and CaO ($\infty$). Although the EDS analysis cannot unambiguously differentiate between these phases, the higher Ca/P mole ratio in HACs may indicate their presence. Such information is relevant, considering that phases with higher Ca/P mole ratio (ACP, CaO and TTCP) form as a result of the most intensive thermal decomposition of the initial HA powder particles in the plasma jet [15,17].

**Cracking occurrence and distribution of Ca/P mole ratio (SEM-EDS)**

The SEM results showed that severe handsaw cutting introduced substantial presence of micro-cracks within the HACs deposited without preheating of substrate ($T_S = 20^\circ$C, Figure 3). Although not presented, it is noteworthy of mentioning that diamond-saw cutting of the same HAC samples produced only a small presence of vertical micro-cracks. The amount of stress introduced by handsaw cutting was much higher com-

![Figure 3. Polished (a) and ground (b) cross-section of HAC deposited at $T_S = 20^\circ$C and corresponding EDS line-scan analyses (c and d). 1-2, 3-4, 5-6, and 7-8 represent the areas with increased Ca/P mole ratio.](image-url)
pared to diamond-saw cutting. Figure 3a shows the polished cross-section of these HACs with two distinctive regions. The first region, with a rough surface, was filled with micro-cracks (designated with „A” in Figure 3a), whereas the second region, with a flat surface, was free of micro-cracks (designated with „R” in Figure 3a). The EDS measurements showed a minor presence of sodium (Na), magnesium (Mg), silicon (Si), chloride (Cl), potassium (K) and iron (Fe) (<0.2 at.%) (Figure 3c). On the other hand, increased amounts of aluminium (Al) were detected within the crack-containing regions. Considering that the presence of Al was undetected in the feedstock HA powder (Figure 2d), it was assumed that the increased amounts of Al detected on the cross-sections of HACs were related to the presence of Al2O3 particles used for polishing of cross-sections. Namely, due to their small size, the Al2O3 particles from water-based suspensions have probably filled the cracks and craters on cross-sections of HACs during the polishing stage. In Figure 3c, it is evident that distribution of Ca, P, and Ca/P changed accordingly to distribution of Al. In order to determine whether these changes were affected by the presence of Al2O3 particles, the cross-section of HAC shown in Figure 3a was ground for several seconds by SiC water-proof abrasive paper (P-2000) to remove the Al2O3 particles. After grinding, the cross-section was examined by the EDS line-scan analysis on the approximately same location. According to Figure 3d, the Ca and P distributions were affected by the Al2O3 presence. On the other hand, by comparing the EDS analysis between 1 and 2 (and 3 and 4, Figure 3a and c) with corresponding analysis between 5 and 6 (and 7 and 8) (Figure 3b and d), the presence of Al2O3 particles did not significantly affect the distribution of the Ca/P mole ratio along the thickness of HAC.

The EDS measurements showed that the Ca/P mole ratio changed roughly between 1.4 and 1.7 within the crack-free regions (Figure 3c), whereas this ratio was >1.8 within the crack-containing regions. The variations of the Ca/P mole ratio within the crack-free regions were close to the variations detected in the initial HA feedstock powder (Figure 2d). For this reason, these regions were attributed to the recrystallized HA (designated with „R” in Figure 3a). On the other hand, the size of the crack-containing regions was much larger than the size of the initial HA feedstock powder. Thus, these regions could not be attributed to the thermally decomposed unmelted or partially molten HA particles of the initial HA feedstock powder. In fact, the cross-sectional examination of HACs showed that the initial HAP particles were nearly fully molten in the plasma jet (the unmelted or semi-molten HA particles of the initial HA feedstock powder could not be observed). For this reason, the crack-containing regions and, thus, an increased Ca/P mole ratio within these regions, were attributed to the hydroxyl-deficient ACP which probably contained CaO and TTCP (designated with „A” in Figure 3a). It is known that periphery of the molten HA particle may be overheated in the plasma jet [17]. The overheating causes the evaporation and loss of P2O5 and, consequently, an increase of the Ca/P mole ratio [17]. Only ~4.4 wt.% change in the phosphate content is sufficient to cause the crystallization of CaO and TTCP from the dephosphorized portion of the melt [17]. When such melt is rapidly cooled upon the impact of molten HA particle onto the substrate or prior-formed HA deposit, the resulting structure will be hydroxyl-deficient ACP phase inside which CaO and TTCP phases may co-exist. In previous study of Hesse et al. [18], the XRPD analysis have shown the relation between the ACP, CaO and TTCP contents. According to their results, the decrease in the ACP content, which is the highest in the interface area due to the highest cooling conditions, has followed the decrease in the CaO and TCP contents. These results are analogous to the results of the line-scan EDS analysis of HAC’s cross-sections, presented in the review article of Surmenev [19], which has shown an increase in the Ca/P mole ratio in the near-interface region of HACs due to a presence of most intensively decomposed products of HA phase in the high-temperature plasma jet.

Further analysis showed that preheating of substrate at T5 = 100 °C noticeably reduced cracking of the coating’s scale caused by the handsaw cutting (Figure 4a). When substrate was preheated at T5 = 200 °C, the cracking was almost imperceptible (Figure 4b). On the other hand, according to EDS-line-scan analyses presented in Figure 4c and d, the preheating of substrate insignificantly affected the variation of the Ca/P mole ratio (at least within the investigated T5 range). Although the crack-containing regions were nearly absent when substrates were preheated at T5 = 200 °C (Figure 4b), the variations in the Ca/P mole ratio indicated that the presence of the impurity phases was unchanged (Figure 4d).

HA splats morphology and cross-sectional microstructure (LM and MRS)

Figure 5a–c show chemically etched cross-sections of HACs deposited at different T5. The darkest spherical-like and/or ellipsoid-like objects were identified as pores. The recrystallized HA regions (light regions) were etched and were intercepted with chemically etched ACP regions (darker regions). It is clear from Figure 5b and c that recrystallized HA regions appeared thinner and finer compared to that in Figure 5a. This result implied that preheating of substrate caused the formation of thinner HA splats. The recrystallized HA regions were smaller in size and more evenly dispersed in HACs.
Figure 4. Polished cross-sections of HAC deposited at $T_s = 100$ (a) and 200 °C (b) and corresponding EDS line-scan analyses (c and d).

Figure 5. Chemically etched cross-sections of HACs deposited at $T_s = 20$ (a), 100 (b) and 200 °C (c) and corresponding MRS spectra (d–f).
when substrate preheating was employed. This result is in accordance with the results of Saber-Samandari [8].

In general, the preheating of substrate enables a wider spreading of HA splats on the surface of the substrate or prior-formed HA deposit and, thus, the formation of thinner HA splats [4,8]. For this reason, a good intersplat contact may be achieved, which leads to a higher cohesion strength of HACs. The last might explain the absence of cracking caused by severe cutting in HACs deposited at higher $T_s$ in the present study. On the other hand, taking into account the brittle nature of ACP phase [4], the recrystallized HA in ACP matrix could be observed as an additional barrier for propagation of micro-cracks. In this regard, the distribution of recrystallized HA (OA) in the substrate or prior-formed HA deposit, it was assumed that higher initial substrate temperatures ($T_s$) might cause the observable differences in contents of these phases.

**CONCLUSIONS**

In the present study, the SEM-EDS results showed that severe cutting conditions introduced cracking within the as-plasma-sprayed HACs. The cracking was localized within the regions with an increased Ca/P mole ratio (>1.8). The phase composition of these regions was dominantly attributed to the hydroxyl-deficient ACP. Further SEM-EDS analysis showed that the substrate preheating promoted an increased cracking resistance of HACs. In contrast to the absence of microracks in HACs deposited at higher $T_s$, MRS and EDS analyses implied that the substrate preheating did not cause significant changes in the local phase composition. On the other hand, the LM analysis showed a noticeable thinner HA splats and finer distribution of recrystallized HA regions in HACs deposited at higher $T_s$. These results implied that the effect of the splat formation mechanism on the resulting distribution of amorphous and recrystallized regions in HACs might play an important role regarding the cracking resistance of as-plasma-sprayed HACs.

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**REFERENCES**


IZVOD

LOM IZAZVAN SEČENJEM PLAZMA SPREJ HIDROKSIAPATITNIH PREVLAKA I NJEGOVA VEZA SA STRUKTURNIM SVOJSTVIMA PREVLAKA NANEŠENIH PRI RAZLIČITIM POLAZNIM TEMPERATURAMA SUBSTRATA

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(Naučni rad)

Veliki broj studija je pokazao da je čvrstoća (kohezija i adhezija) hidroksiapatitnih (HA) prevlaka dobijeni h primenom plazma sprej postupka od izuzetnog značaja u slučajevima njihovog nanošenja na metalne biomedicinske implantate. Uopšteno, HA prevlake, dobijene ovim postupkom, se formiraju od velikog broja delimično i/ili potpuno istopljenih čestica polaznog HA praha koje se brzo hlađe pri udaru u substrat i/ili prethodno formirani depozit. Na osnovu prethodnog, kohezija HA prevlaka će zavisi od prirode kontakta između individualnih čestica HA depozita nastalih brzim hlađenjem, dok će adhezija zavesti od prirode kontakta između prvog sloja ovih čestica i substrata. Pored rekristalizane HA faze, pri brzom hlađenju HA kapljeva dolazi do formiranja krte amorfnih fosfatnih (ACP) faze. Ukoliko se tokom procesa nanošenja formiraju veći broj susednih dominantno amorfnih individualnih čestica HA depozita, taj deo prevlaka treba da ispoljava minimalni (krteni) otpor razlučivanju. Ako se tokom procesa nanošenja objašnjava minimalni otpor razlučivanju, s obzirom na izraženost ACP faze, u ovom radu je ispitivački proces bio usmeren na obeleženje promena lokalnog faznog sastava i korelacije ovih svojevrednosti sa pojavom loma u prevlakama. Ovaj efekt je posebno bio izražen u HA prevlakama koje nisu nanešene bez predgrevanja substrata. S druge strane, predgrevanje substrata na $T_S = 20, 100, and 200 \degree C$ nakon sečenja, poprečni preseći HA prevlaka su analizirani primenom skening elektronske mikroskopije sa energetsko-disperzivnom spektrometrijom (SEM-EDS), mikro-Ramanove spektroskopije (MRS) i svetlosne mikroskopije (SM) u kombinaciji sa hemijskim nagrizanjem. Ove tehnike su primenjene u cilju praćenja promena promena lokalnog faznog sastava u prevlakama i morfološke individualnih čestica HA depozita sa inicijalom promenom tečnosti u substratu, nakon čega je vršena korelacija ovih svojevrednosti sa pojavom loma u prevlakama. Rezultati ispitivanja su pokazali da su agresivni uslovi sečenja uslovili pojavu lokalizovanog loma u HA prevlakama oboljelenih za velike hlađenje. Ovaj efekat je posebno bio izražen u HA prevlakama koje nisu nanešene bez predgrevanja substrata. S druge strane, predgrevanje substrata na $T_S = 100 \degree C$ je izuzetno efekatno primetno manje prisustvo mikro-prslina u HA prevlakama, dok je predgrevanje na $T_S = 200 \degree C$ izazvalo veće pojavu mikro-prslina. Pritom, značajnije promene u srednjem lokalnom faznom sastavu nisu detektovane. U HA prevlakama kod kojih je predgrevanje uslovilo formiranje individualnih čestica HA depozita i raspodela amorfnih i rekristaliziranih oblasti su bile manje, a oblasti rekristalizane HA faze su bile manje i ravnomerne raspodeljene u zapremini HA prevlaka. Ovi rezultati su ukazali na to da su mehanizam formiranja individualnih čestica HA depozita i raspodela amorfnih i rekristaliziranih oblasti u zapremini HA prevlaka faktori koji mogu značajno da utiču na otpornost na lom kod ove vrste prevlaka.